

Transition métal-non métal dans le composé
 $(\text{BEDT-TTF})_8\text{Hg}_4\text{Br}_{12}(\text{C}_6\text{H}_5\text{Br})_2$

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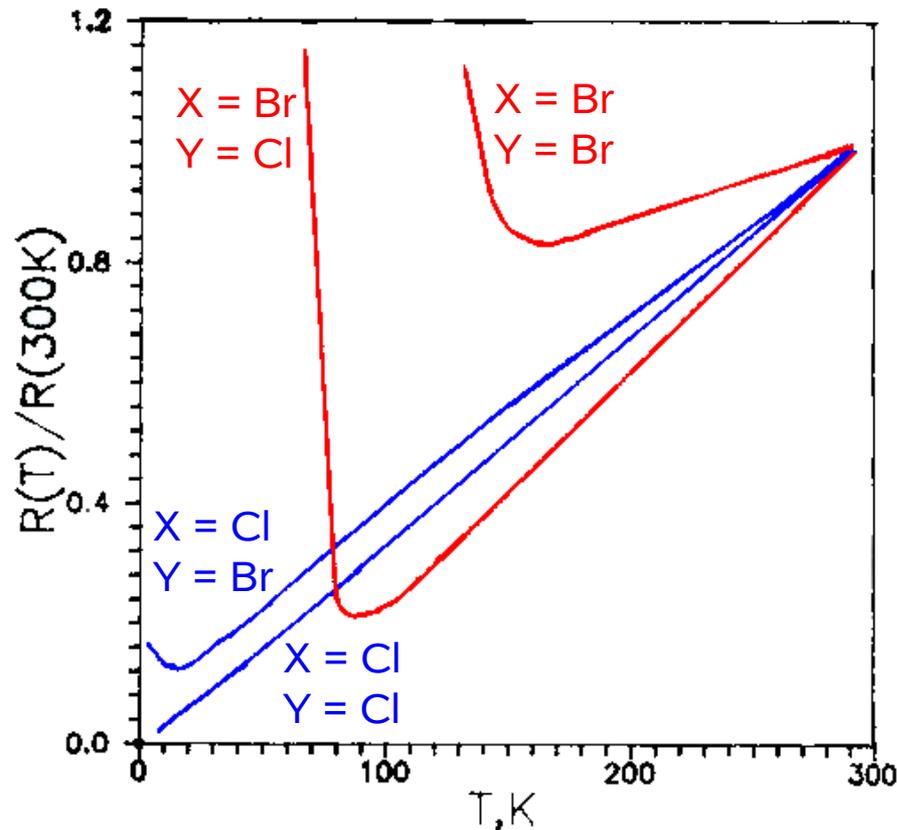
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Motivation:

$(\text{BEDT-TTF})_8\text{Hg}_4\text{X}_{12}(\text{C}_6\text{H}_5\text{Y})_2$ family, where $(X, Y) = (\text{Cl}, \text{Br})$



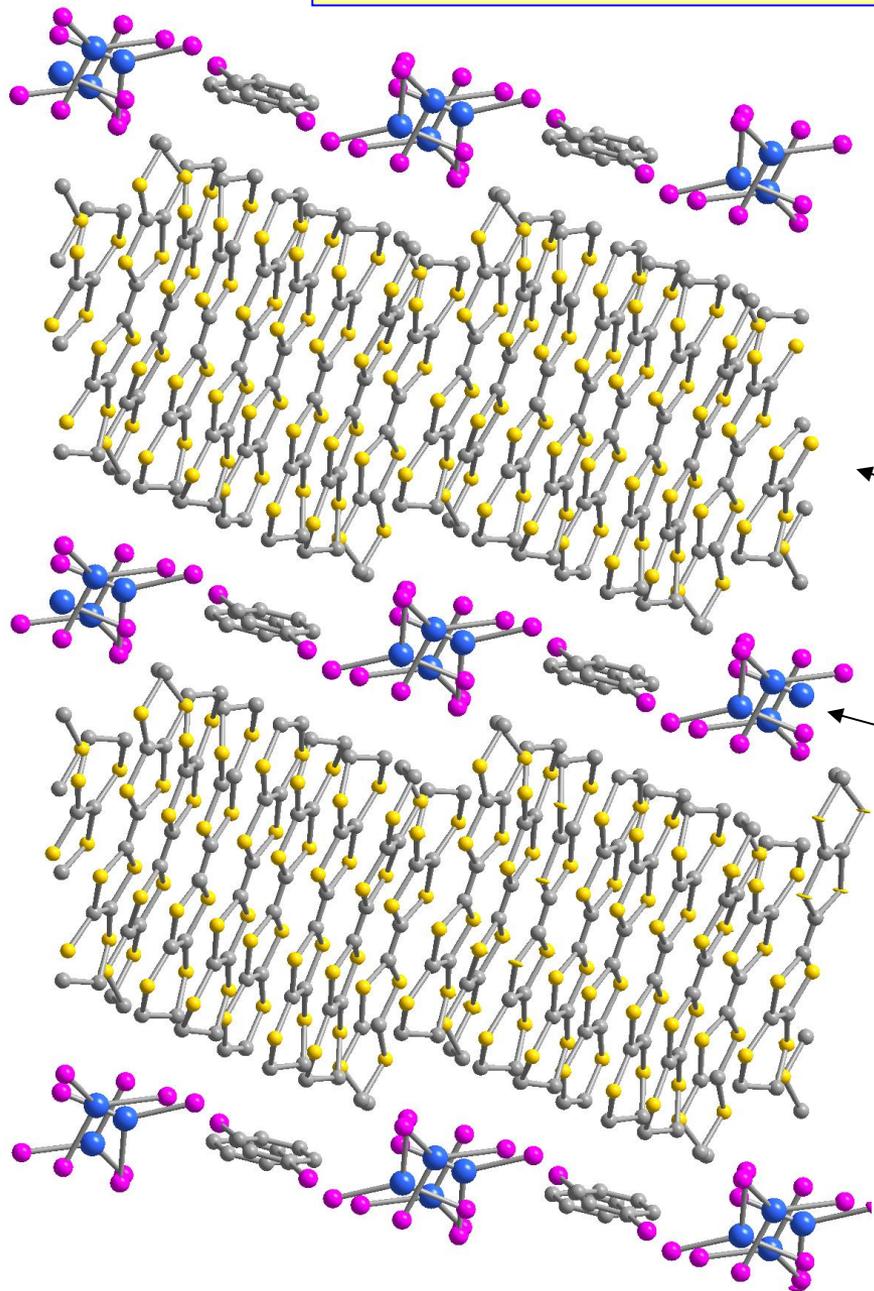
X = Cl: metallic ground-state

X = Br: metal-non metal transition

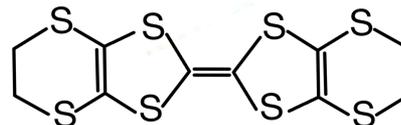
even though the four members of this family are isostructural at room temperature

$(\text{BEDT-TTF})_8\text{Hg}_4\text{X}_{12}(\text{C}_6\text{H}_5\text{Y})_2$: crystalline structure

$\text{X} = \text{Y} = \text{Br}$ (150 K)

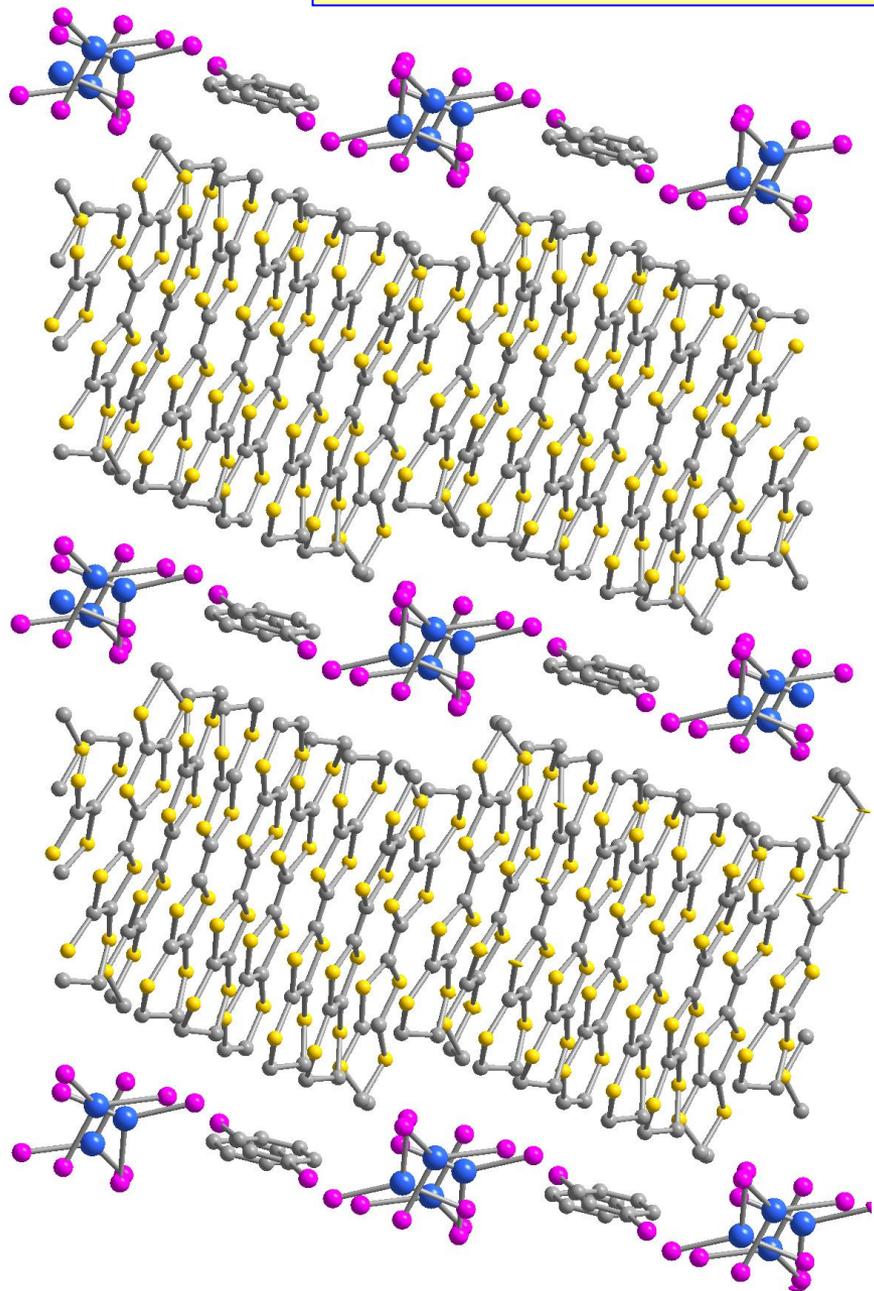


conducting planes:
 $(\text{BEDT-TTF})^{0.5+}$ cation layers

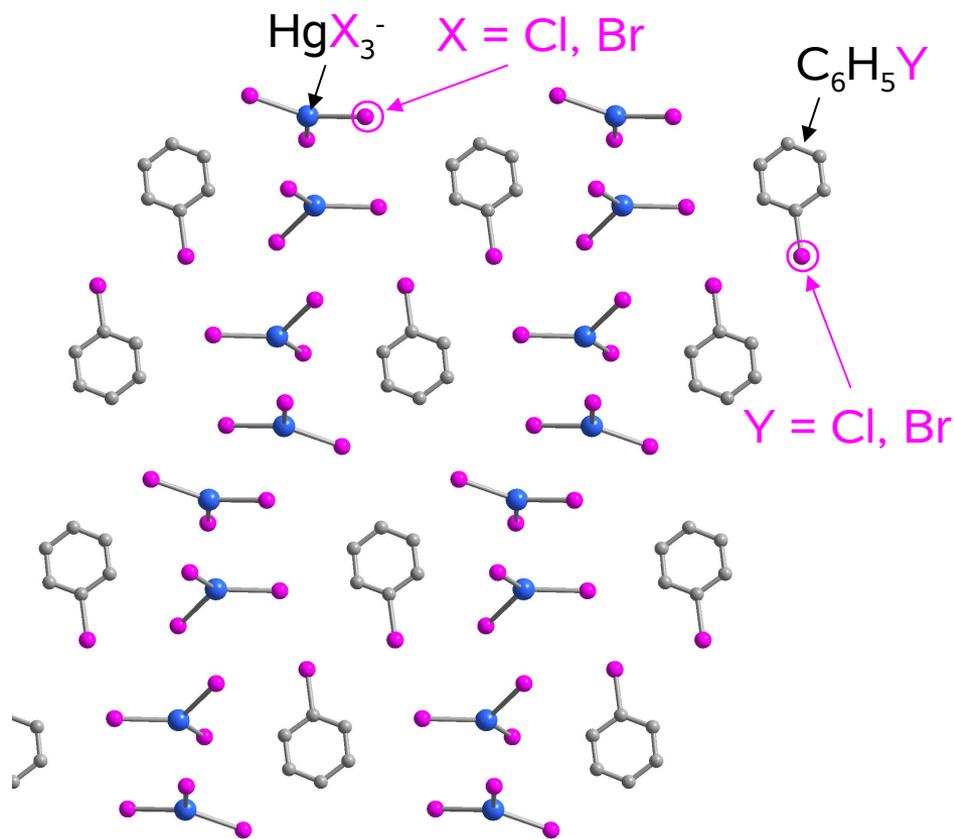


Insulating planes:
 HgX_3^- anion + $\text{C}_6\text{H}_5\text{Y}$ (solvent)

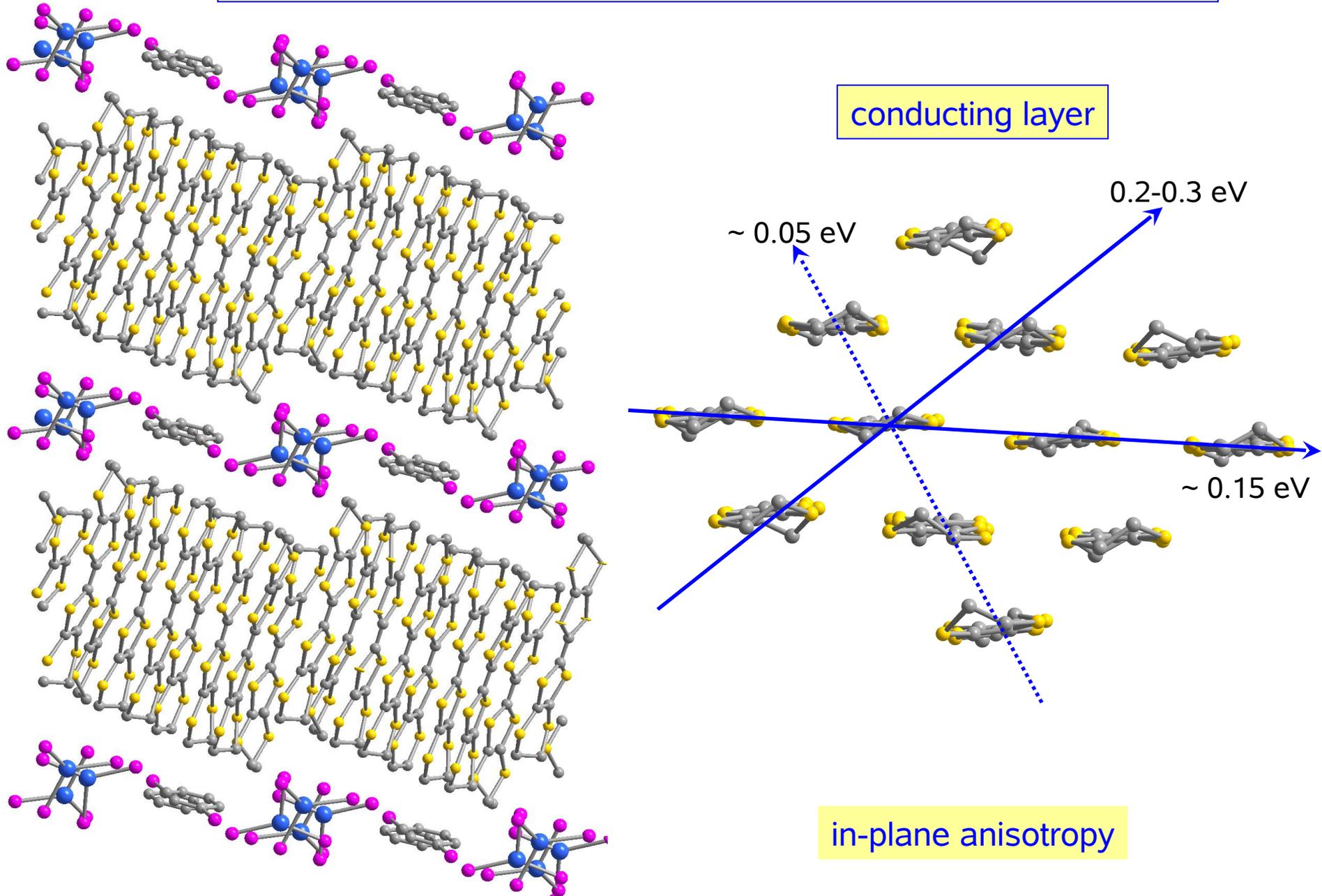
$(\text{BEDT-TTF})_8\text{Hg}_4\text{X}_{12}(\text{C}_6\text{H}_5\text{Y})_2$: crystalline structure



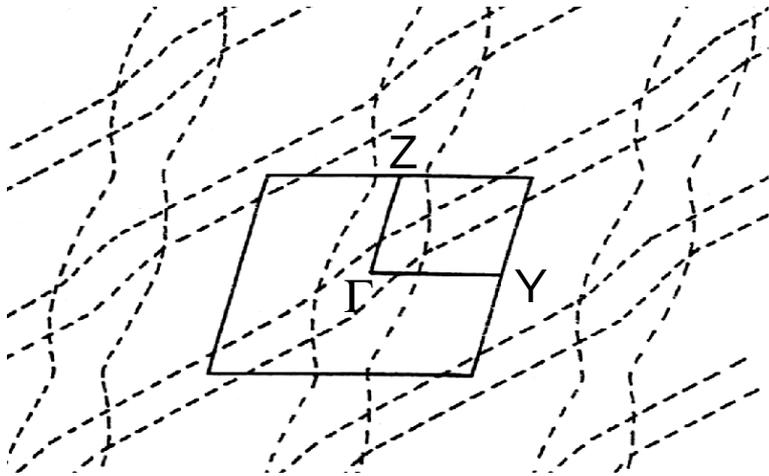
insulating layer



$(\text{BEDT-TTF})_8\text{Hg}_4\text{X}_{12}(\text{C}_6\text{H}_5\text{Y})_2$: crystalline structure



Electronic structure (Extended Hückel)

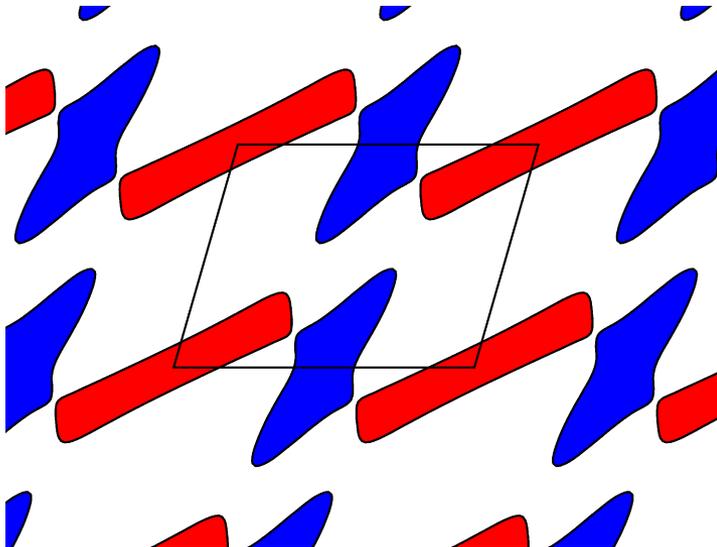


Two pairs of crossing q-1D sheets

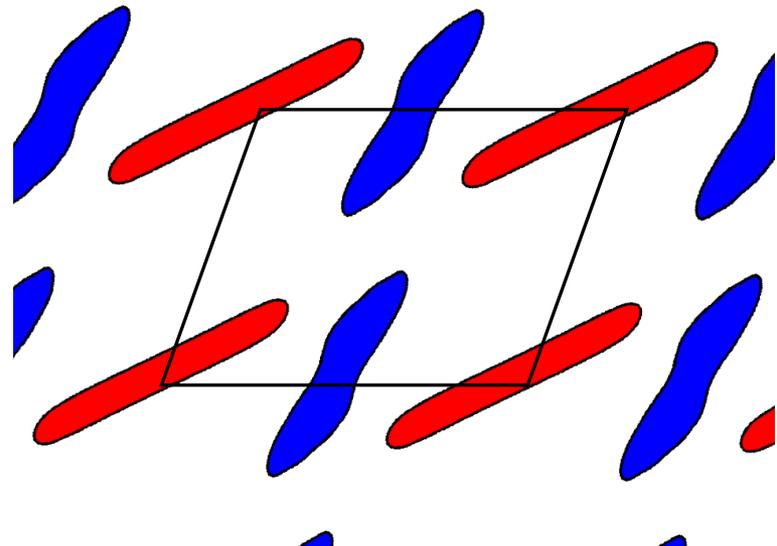
Degeneracy removals yields compensated **electron** and **hole** orbits

→ 2D Fermi surface

$X = \text{Cl}, Y = \text{Br}$: metallic ground-state



$X = Y = \text{Br}$:
metal non-metal transition at ~ 150 K.
Hidden nesting \rightarrow density wave ?



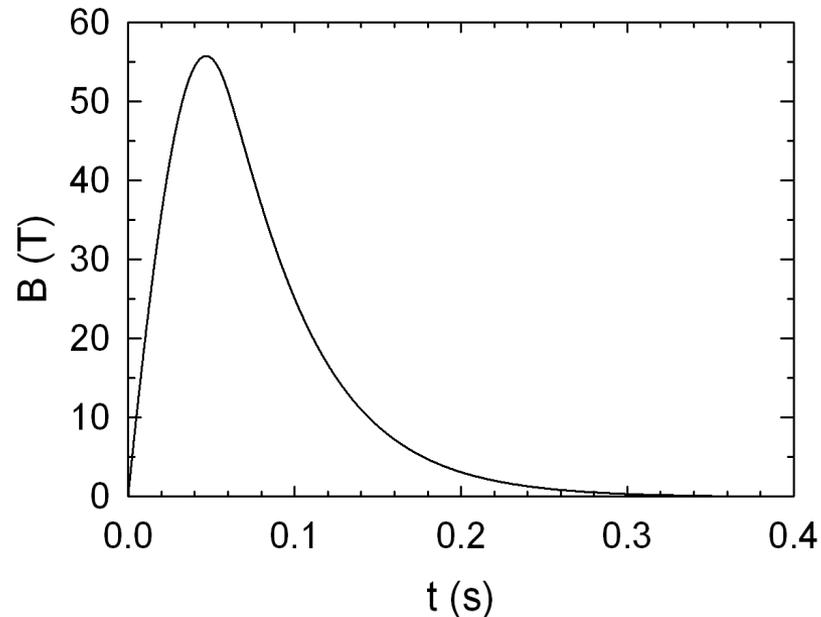
Experiments

Quantum oscillations

closed orbits \rightarrow test for Fermi surface

- Periodic in $1/B$
- Frequency proportional to orbit area (in k-space)
- Temperature and field-dependence yield physical parameters

Interlayer magnetoresistance in pulsed magnetic field (55 T)
 \rightarrow Shubnikov-de Haas oscillations



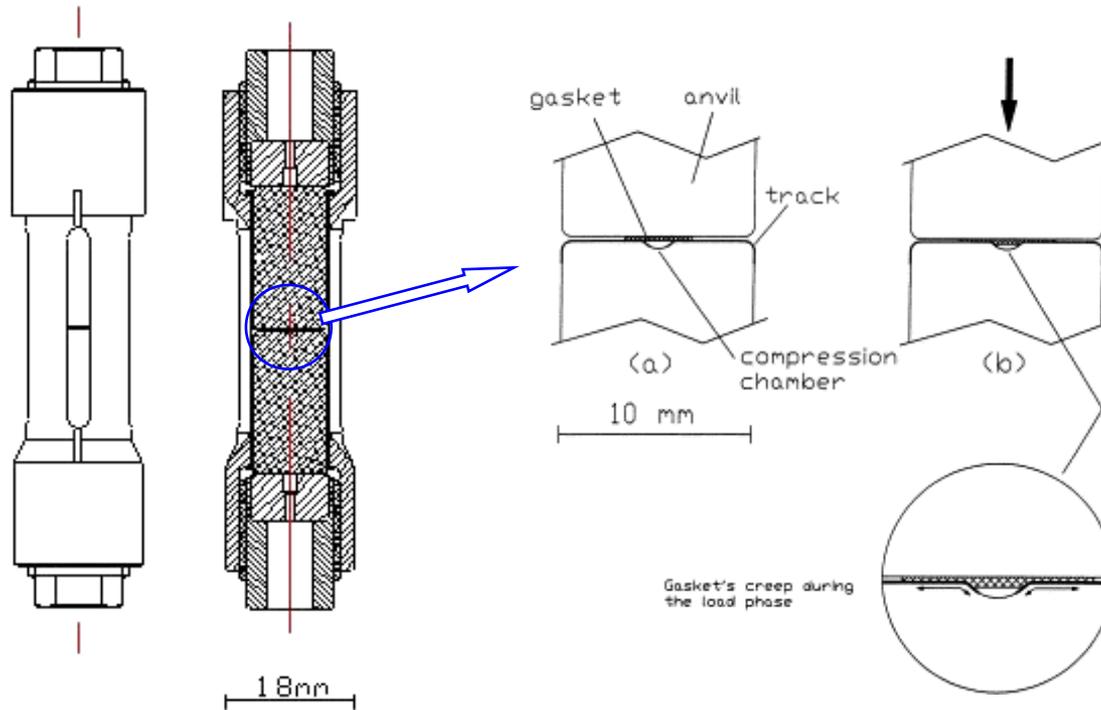
Experiments

Applied pressure

powerful tool for tuning physical properties

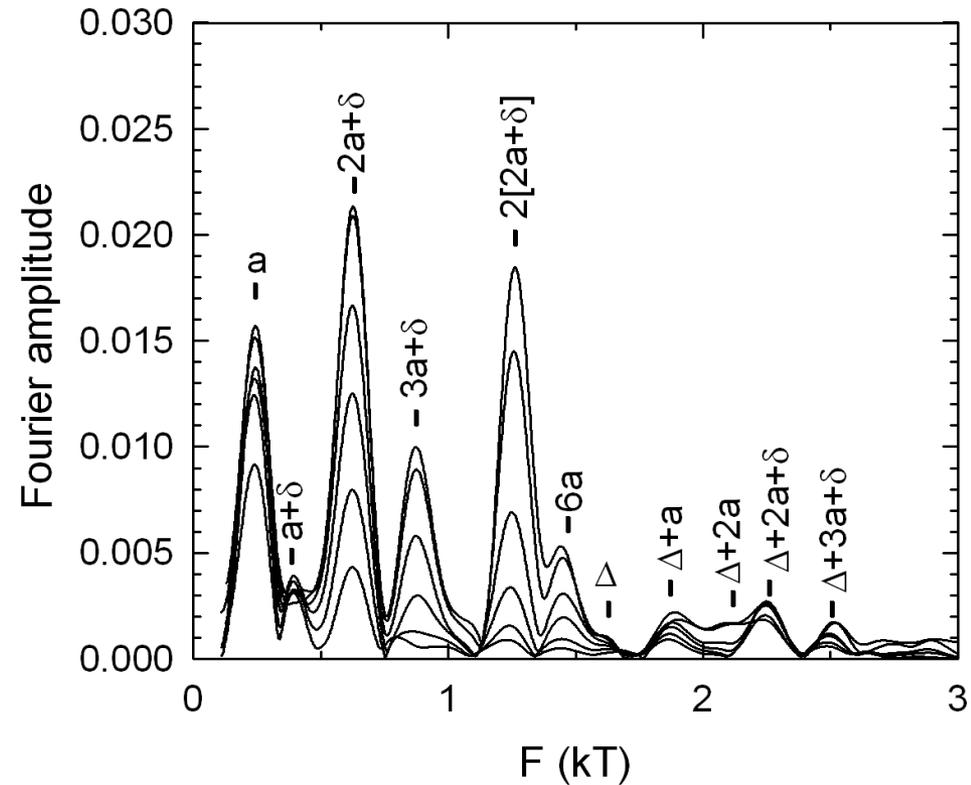
Need for isothermal transport measurements at liquid helium temperatures in pulsed fields

Pressure cell: zirconia anvils – $P_{\text{max}} = 1.2 \text{ GPa}$



Ambient pressure data for X = Cl: metallic ground state

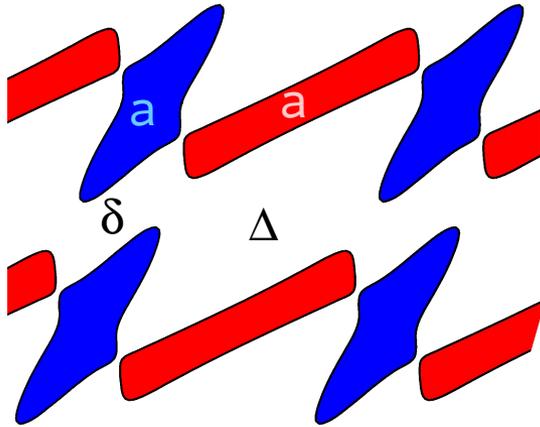
Fourier analysis



a lot of frequencies are observed

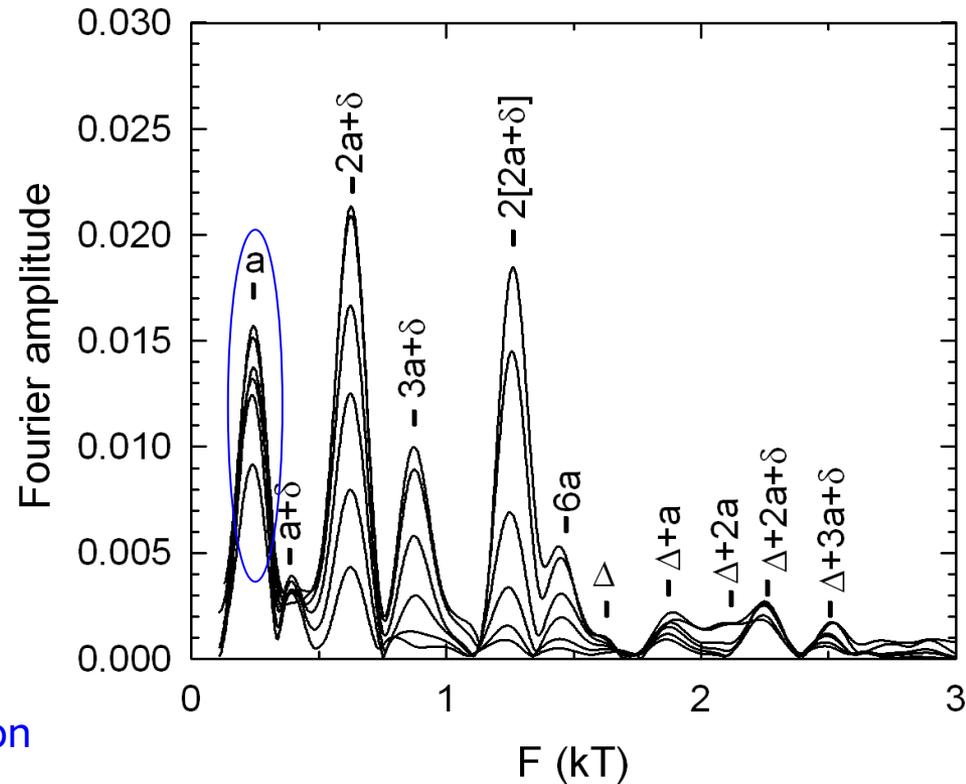
Ambient pressure data for X=Cl, Y=Br (metallic ground state)

Linear combinations of the frequencies linked to the basic electron and hole orbits (a) and of the δ and Δ pieces .



Closed magnetic breakdown orbits
 Quantum interference paths
 Forbidden orbits

Landau bands
 Chemical potential oscillation



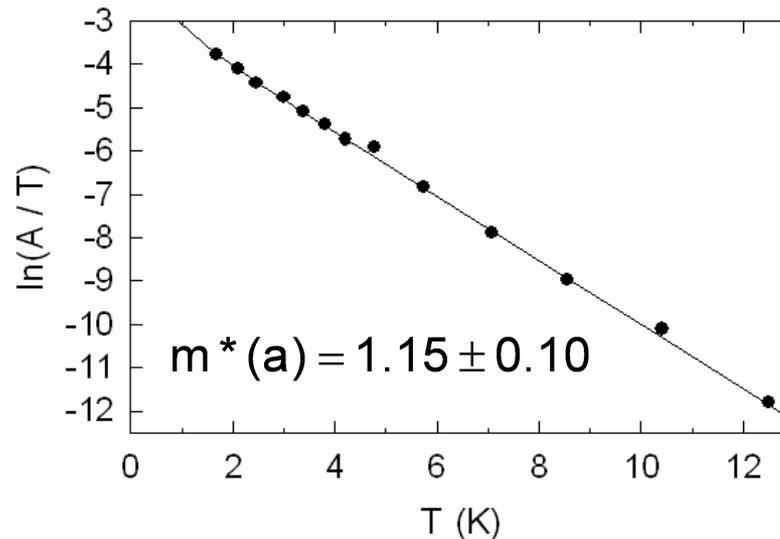
Model system for the study of quantum oscillations in networks of coupled orbits

Derivation of physical parameters: Lifshits-Kosevich formalism

Fourier amplitude: $A \propto R_T R_D R_{MB}$

at a given field value: Fermi-Dirac smearing $A \propto R_T = \frac{Tm^*}{B} / \sinh\left(\frac{u_0 Tm^*}{B}\right)$

temperature dependence yields effective mass (m^*)



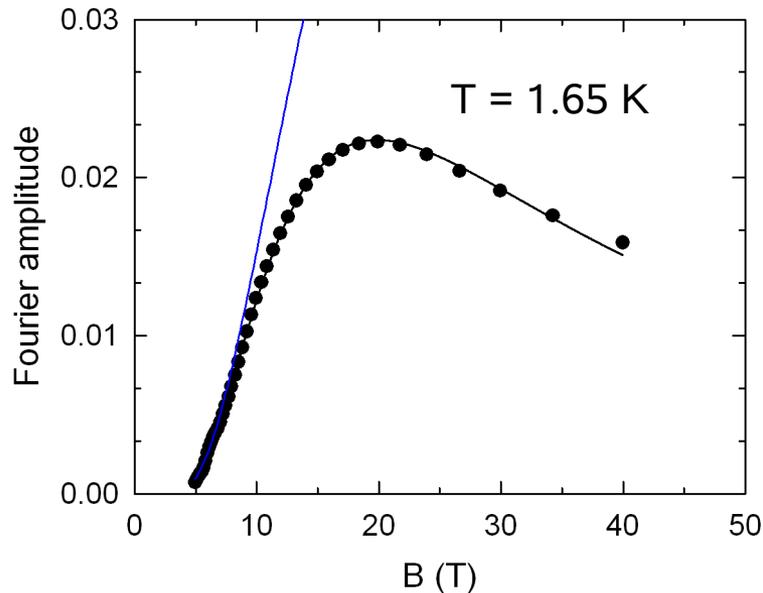
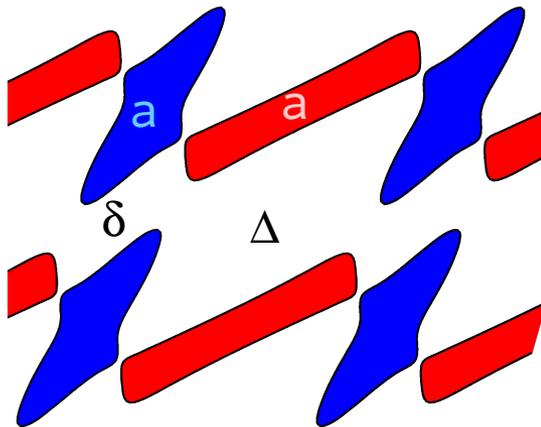
Derivation of physical parameters: Lifshits-Kosevich formalism

Fourier amplitude: $A \propto R_T R_D R_{MB}$

At a given temperature:

Dingle damping factor: $R_D = \exp\left(-\frac{u_0 T_D m^*}{B}\right)$ $T_D = \frac{\hbar}{2\pi k_B \tau}$ τ : scattering time

Magnetic breakdown damping factor: $R_{MB} = [1 - \exp(-B_0/B)]^2$ B_0 : MB field

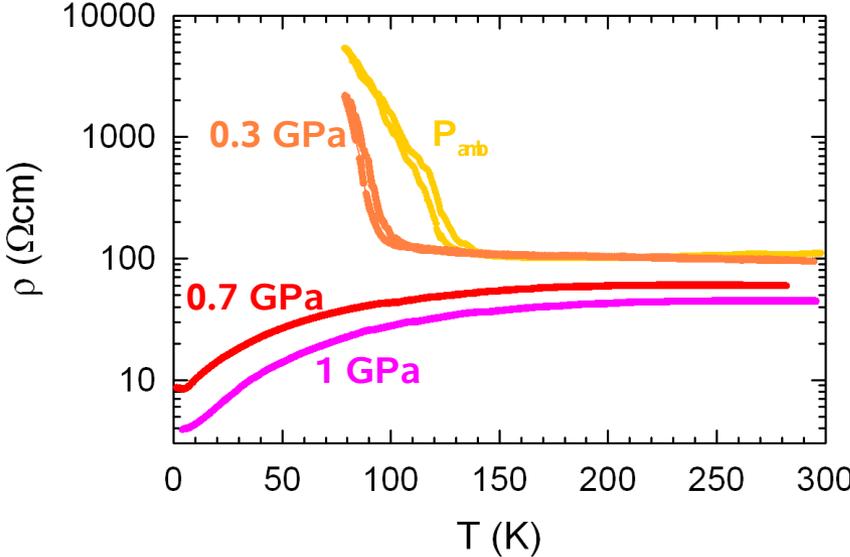
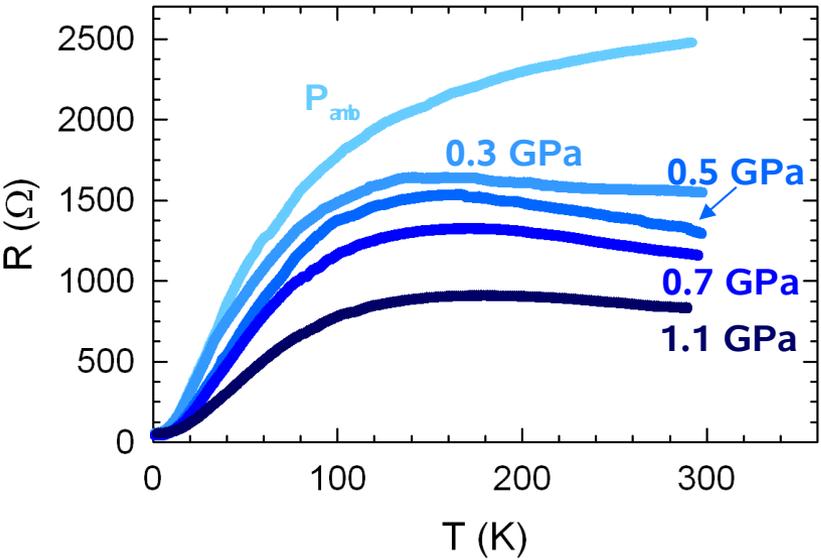


$B_0 = (35 \pm 10) \text{ T}$
 $T_D = (0.2 \pm 0.2) \text{ K}$
 \downarrow
 $\tau^{-1} = (1.7 \pm 1.7) \times 10^{11} \text{ s}^{-1}$
 very good crystals!

Effect of applied pressure: zero-field resistance

X = Cl (metallic ground state)

X = Br: pressure-induced metallic state



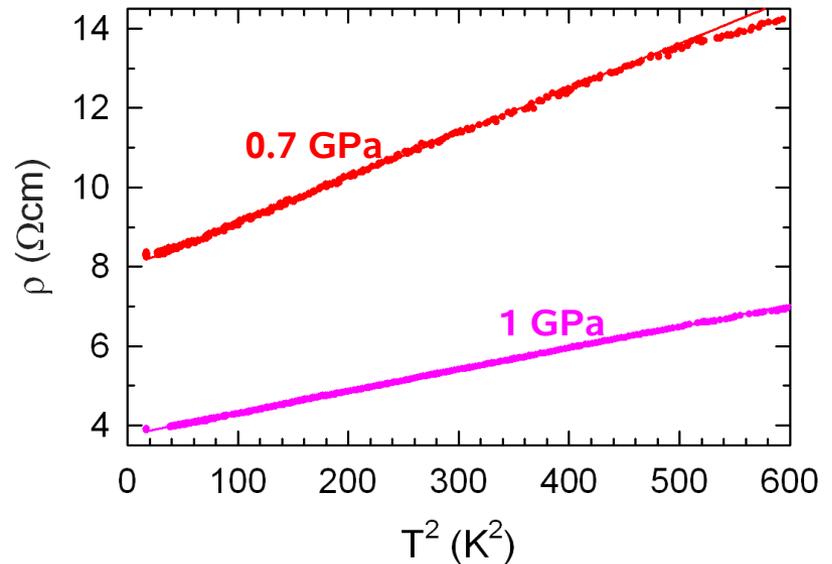
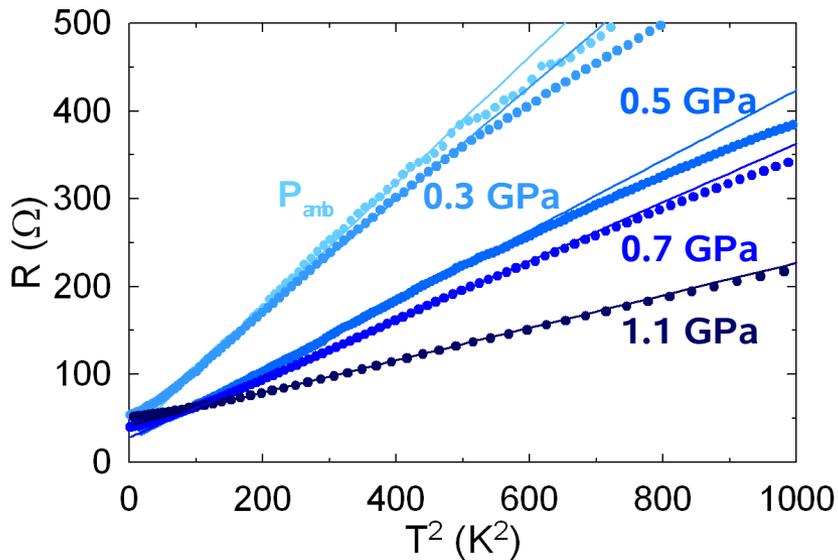
X = Cl: bump under pressure
Defects and (or) correlations

X = Br at low pressure: hysteresis
at high pressure: metallic state

Effect of applied pressure: zero-field resistance at low temperature

X = Cl (metallic ground state)

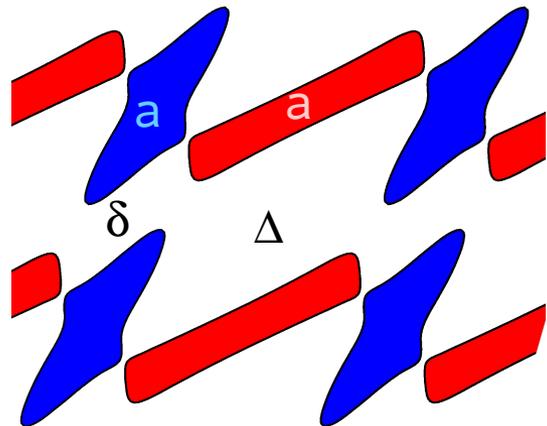
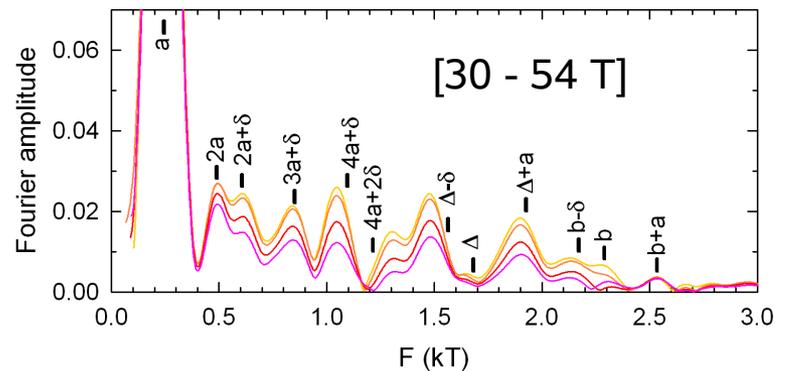
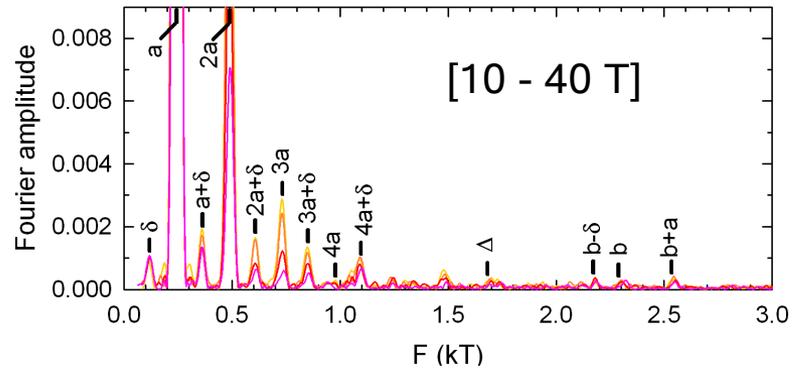
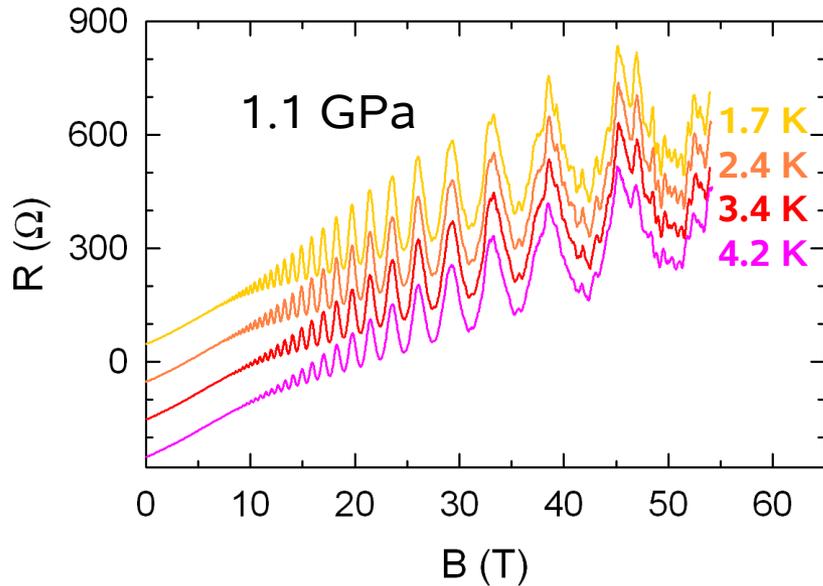
X = Br: pressure-induced metallic state



X = Cl and X = Br at high pressure:
 $R = R_0 + AT^2$
→ correlated Fermi liquid
A decreases as applied pressure increases

Effect of applied pressure: SdH oscillations

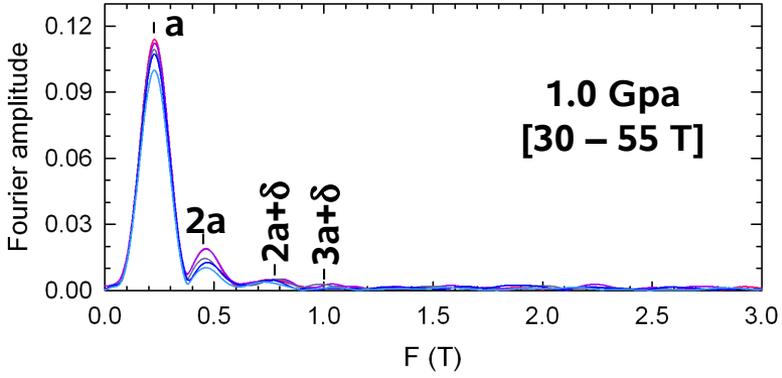
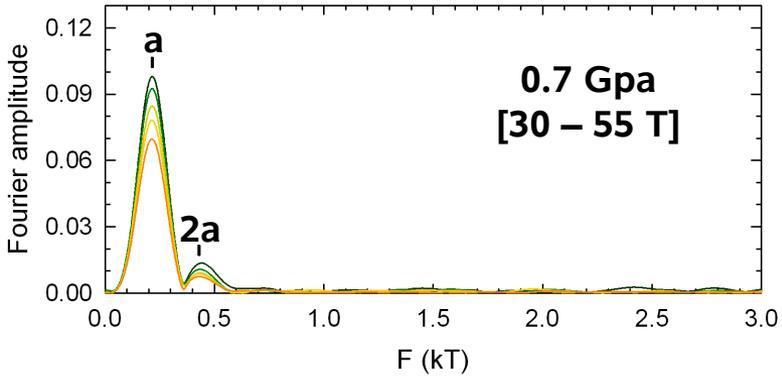
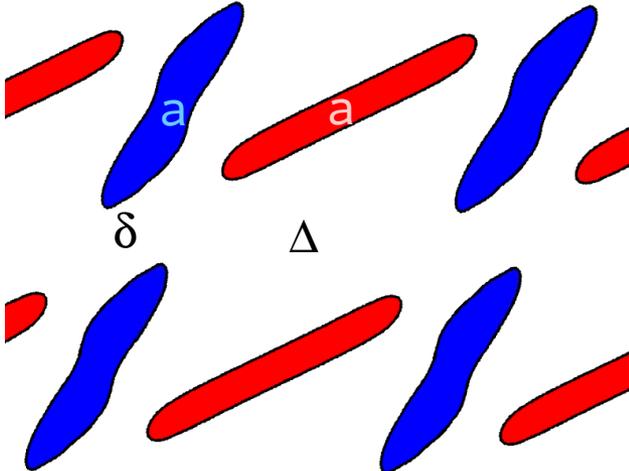
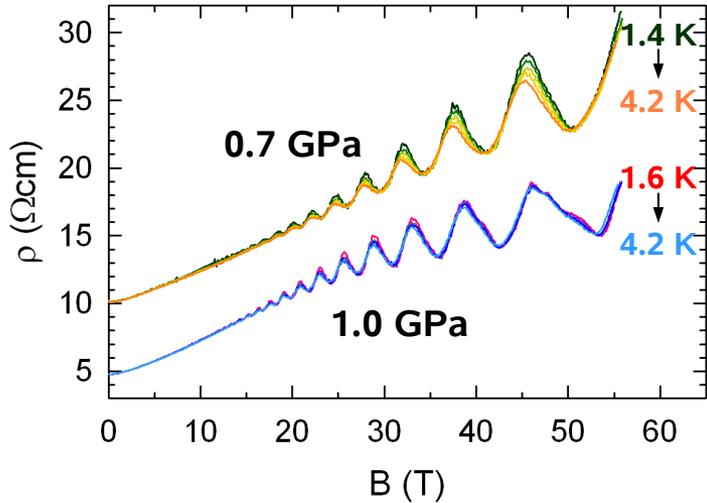
$X = \text{Cl}$ (metallic ground state)



Still many frequency combinations
(magnetic breakdown)
Same features as at ambient pressure

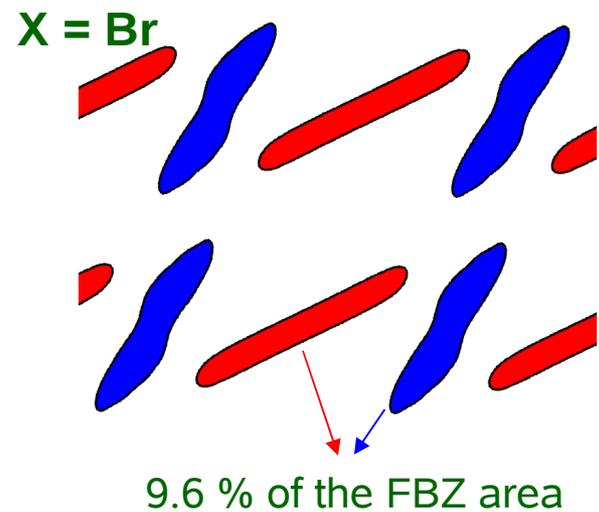
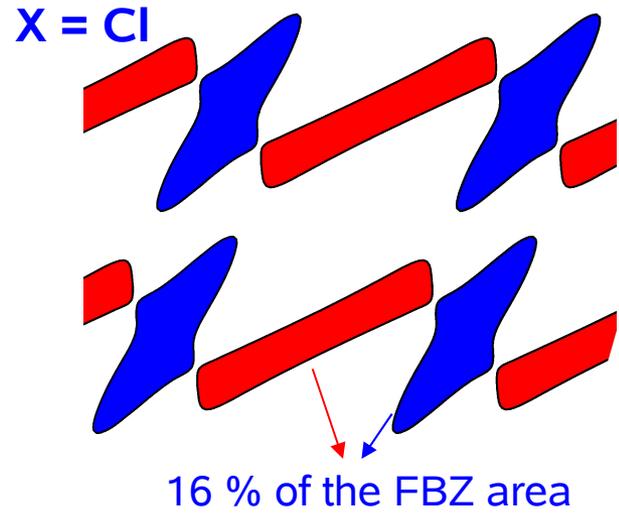
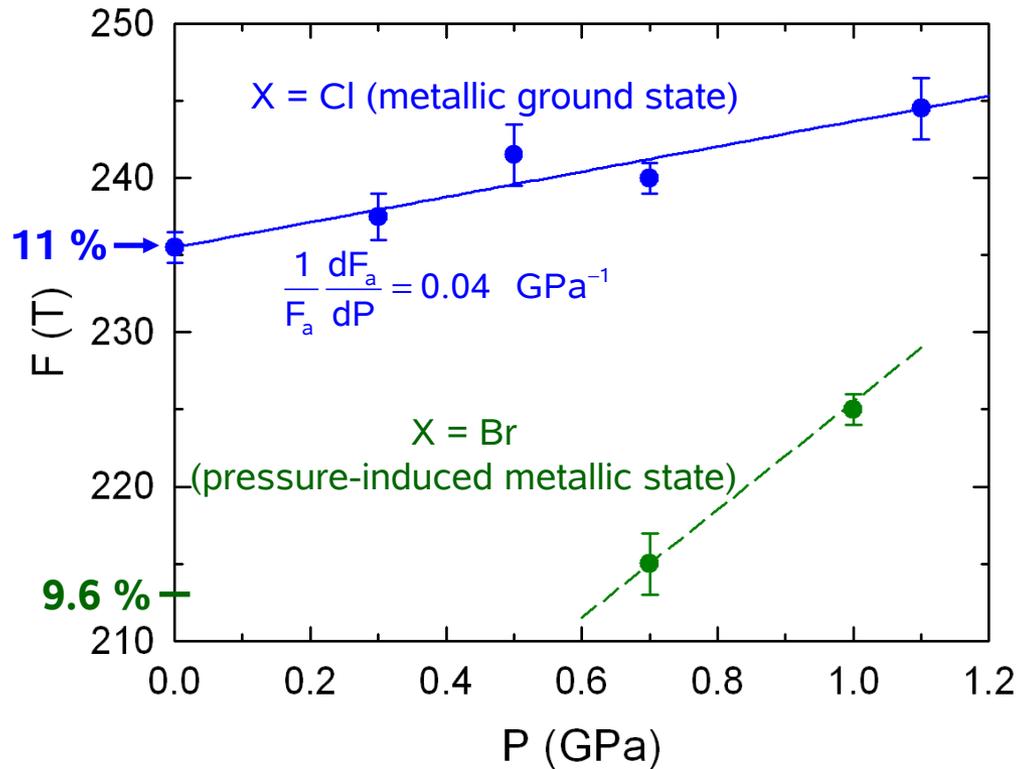
Effect of applied pressure: SdH oscillations spectra

X = Br (pressure-induced metallic ground state)



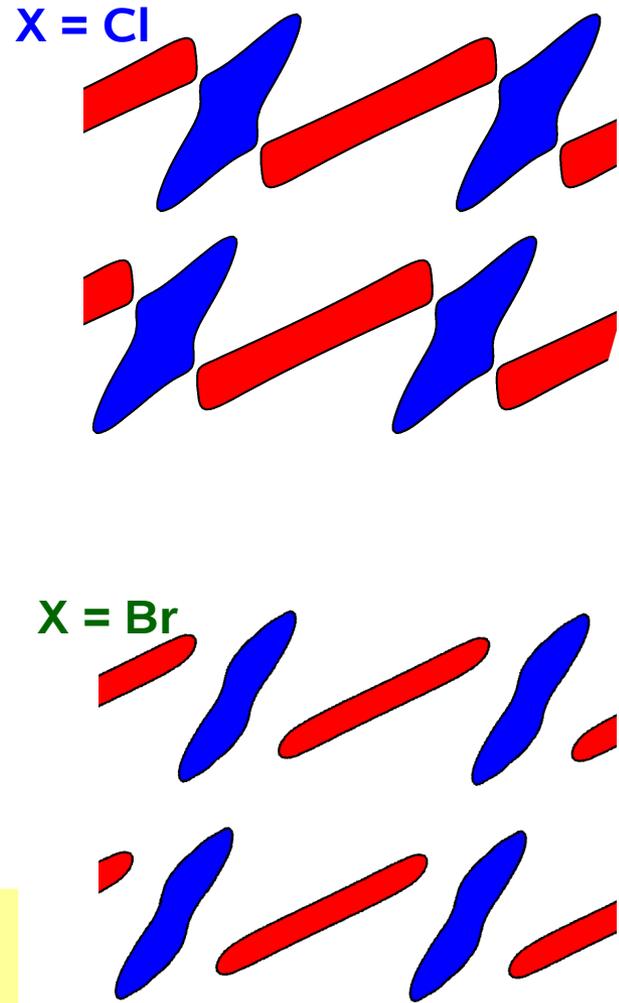
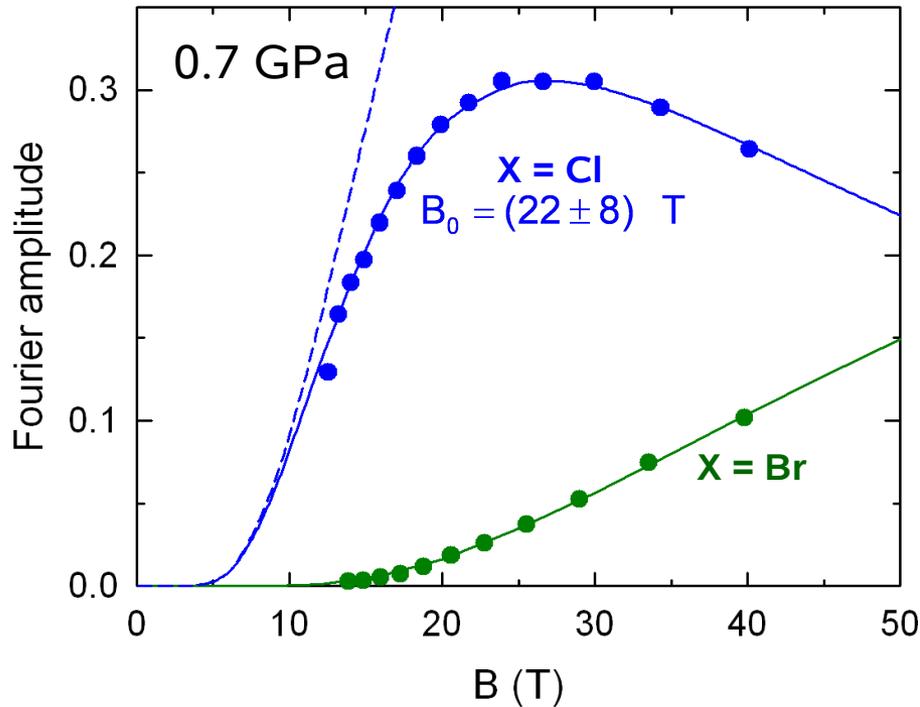
Almost no frequency combinations:
suggests magnetic breakdown gap larger
than for X = Cl

Effect of applied pressure: Oscillations frequency linked to basic orbits



Pressure sensitivity (For $X = \text{Cl}$) similar to most of other organic metals
 Orbits area in good agreement with band structure calculations

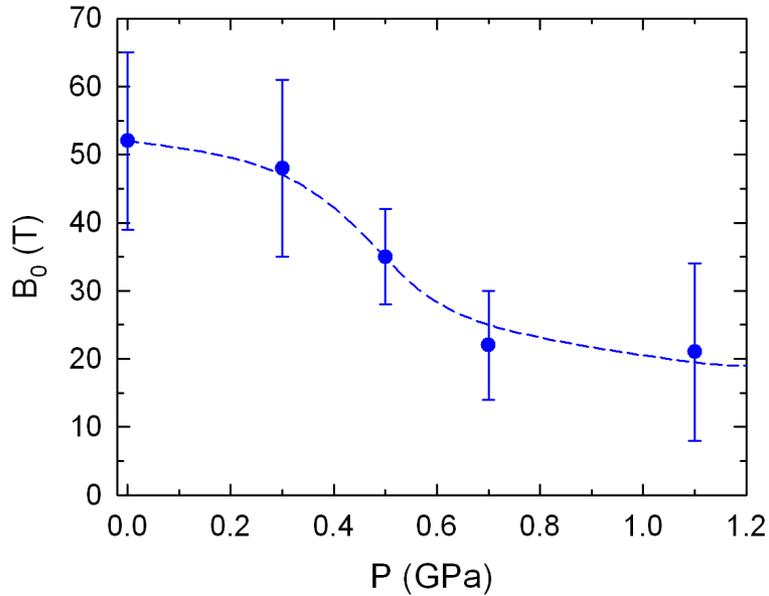
Effect of applied pressure: Magnetic breakdown field



Magnetic breakdown not observed for X = Br
Accounts for the absence of frequency combinations.
Consistent with band structure calculations

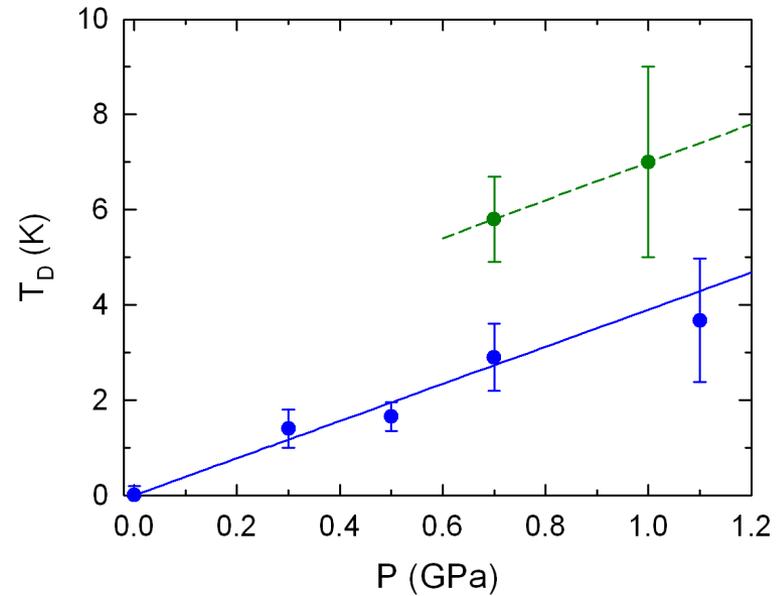
Effect of applied pressure:

Magnetic breakdown field



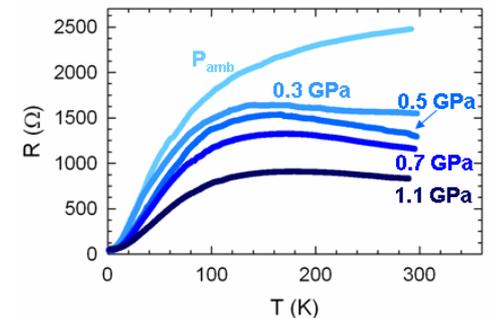
Strong decrease of the MB field

Dingle temperature (\propto scattering rate)

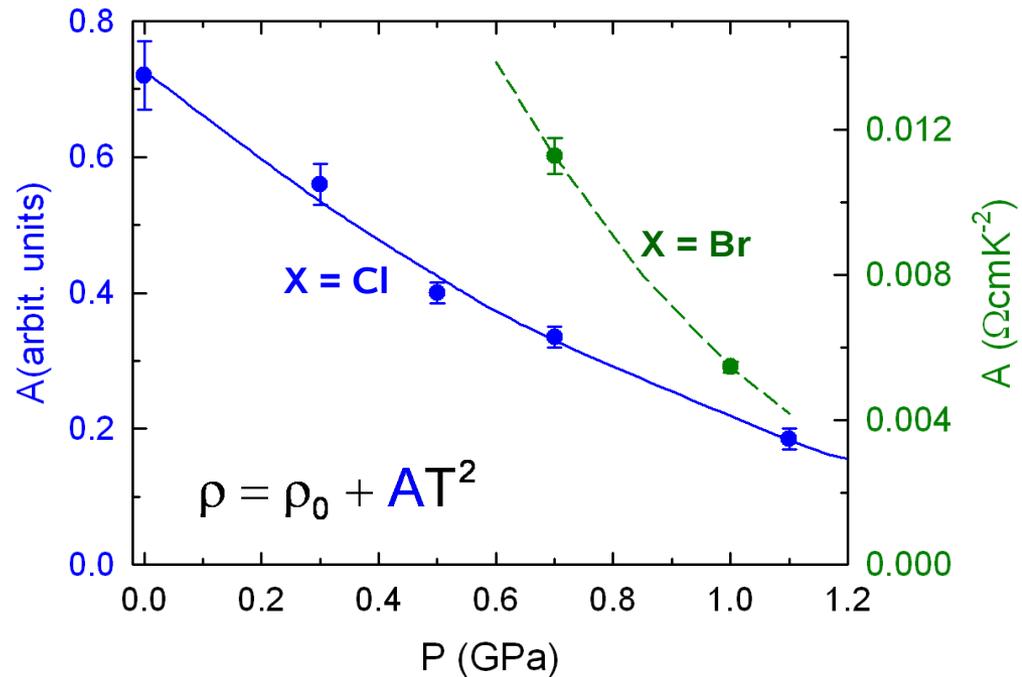
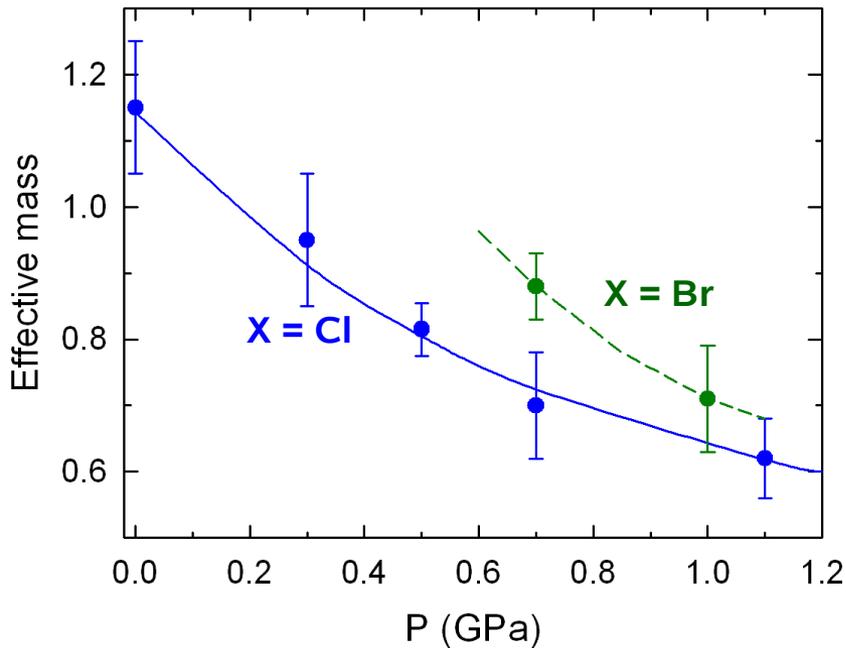


Strong (and reversible) increase of the scattering rate

may explain zero-field resistance:



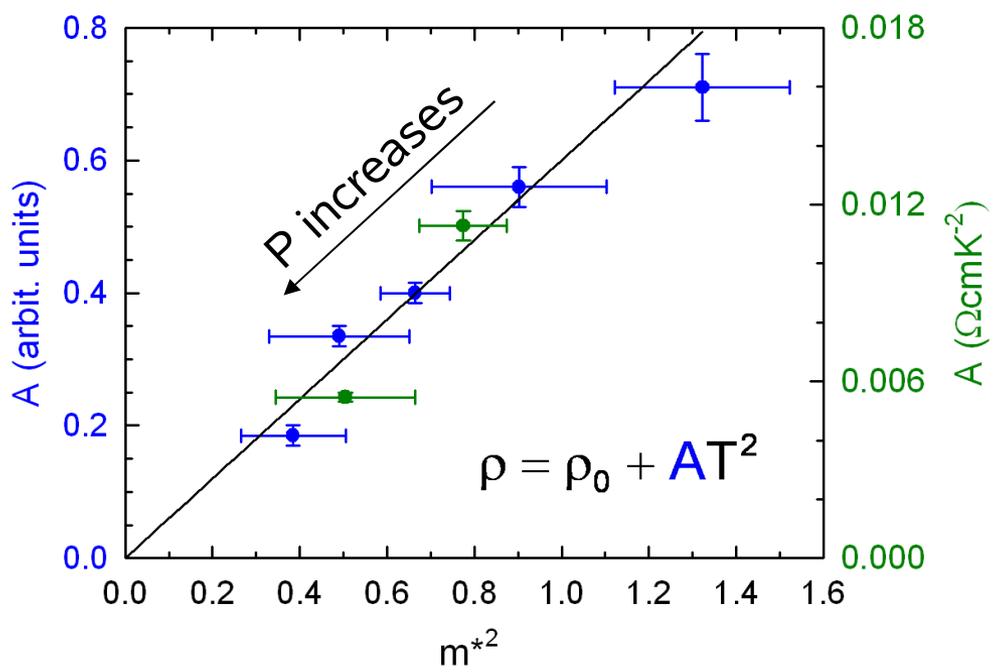
Effect of applied pressure: Effective mass and zero-field resistance



Strong decrease of both the effective mass and the coefficient (A) of the T^2 law of the zero-field resistance.

Effect of applied pressure: Effective mass and zero-field resistance

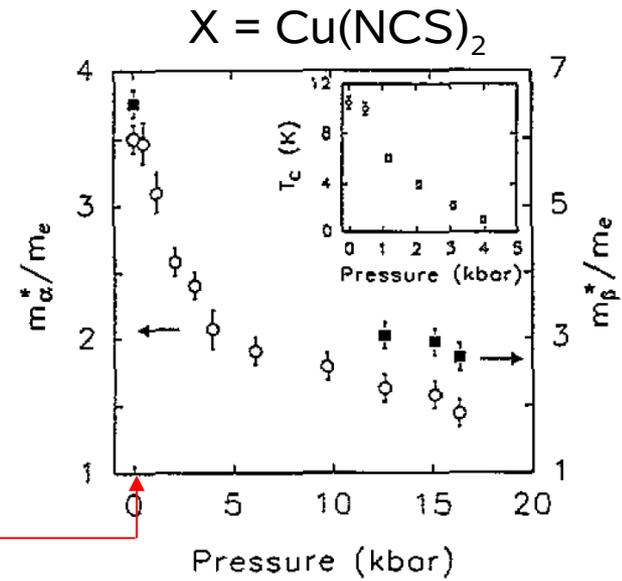
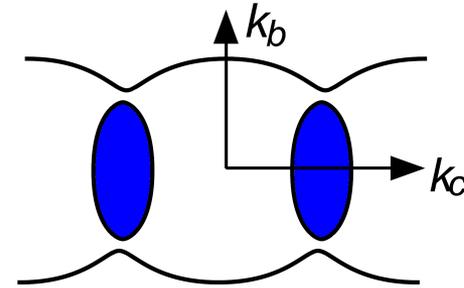
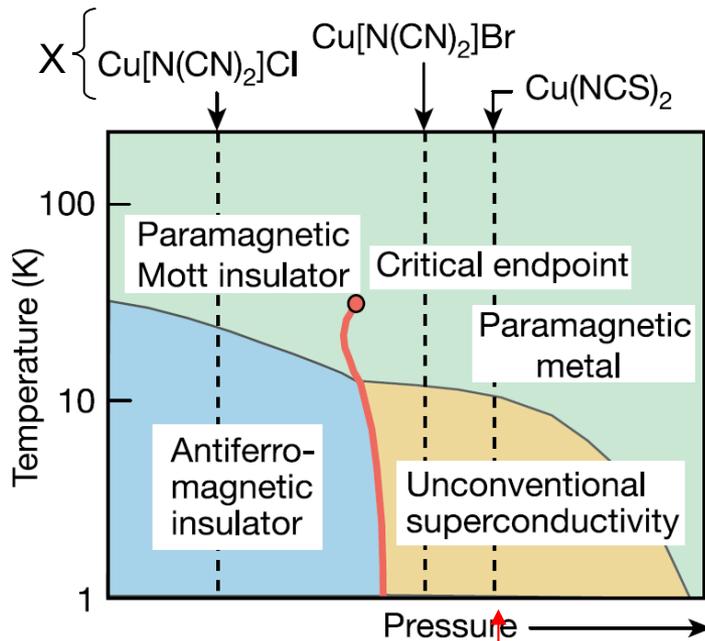
Low temperature resistivity driven by electron correlations: $A \propto m^{*2}$



A roughly scales with m^{*2}

In the framework of the Brinkman-Rice scenario a divergence of the effective mass as approaching a Mott transition should be observed

Mott insulator state already reported for phase diagrams of organic conductors, although mainly in κ -(BEDT-TTF)₂X salts, with different Fermi surface



Summary

Good agreement with band structure calculations in the metallic state (Extended Hückel)

Zero-field interlayer resistivity:

- typical of strongly correlated Fermi liquid at low temperature (T^2 law)
- contribution of disorder under applied pressure at higher temperatures

Effective mass strongly decreases as pressure increases:

could suggest a Brinkman-Rice scenario (divergence of m^*) for $X = \text{Br}$

Next steps

For $X = \text{Br}$:

X-ray data at low temperature (charge density wave, charge ordering?)

Magnetoresistance data in the pressure range 0.3 - 0.7 GPa (i.e. within the metal-non metal transition) to check the behaviour of the effective mass